

## Micron

Images are for reference only.

See Product Specifications for product details.

Buy MT47H512M4EB-25E:C TR with confidence from

MT47H512M4EB-25E:C TR

Micron

Part Number: MT47H512M4EB-25E:C TR

Manufacturer Micron Technology

**Description** IC DRAM 2G PARALLEL 60FBGA

Data sheet: MT47H256M8, MT47H128M16, MT47H512M4

RoHs Status: Lead free / RoHS Compliant

Ship From: Hong Kong

Shipment Way: DHL/Fedex/TNT/UPS/EMS

RFQ

RFQ

RFQ

RFQ

**RFQ** 

RFQ

RFQ

RFQ

**RFQ** 

RFQ

RFQ

**RFQ** 

RFQ

RFQ

RFQ

RFQ

RFQ

RFQ

RFQ

RFQ

Component-World.HK, 1 Year Warranty

Request For Quotation

RODUCT PARAMETER			
Part Number	MT47H512M4EB-25E:C TR	Manufacturer	Micron Technology
Description	IC DRAM 2G PARALLEL 60FBGA	Lead Free Status / RoHS Status	Lead free / RoHS Compliant
Quantity Available	4367 pcs	Data sheet	MT47H256M8, MT47H128M16, MT47H512M4
Category	Integrated Circuits (ICs)	Write Cycle Time - Word, Page	15ns
Voltage - Supply	1.7 V ~ 1.9 V	Technology	SDRAM - DDR2
Supplier Device Package	60-FBGA (9x11.5)	Series	-
Packaging	Tape & Reel (TR)	Package / Case	60-TFBGA
Other Names	MT47H512M4EB-25E:C TR-ND MT47H512M4EB-25E:CTR	Operating Temperature	0°C ~ 85°C (TC)
Mounting Type	Surface Mount	Moisture Sensitivity Level (MSL)	3 (168 Hours)
Memory Type	Volatile	Memory Size	2Gb (512M x 4)
Memory Interface	Parallel	Memory Format	DRAM
Lead Free Status / RoHS Status	Lead free / RoHS Compliant	Detailed Description	SDRAM - DDR2 Memory IC 2Gb (512M x 4) Parallel 400MHz 400ps 60-FBGA (9x11.5)
Clock Frequency	400MHz	Base Part Number	MT47H512M4
Access Time	400ps		

RFQ Email: info@Components-World.com

Manufacturers: Micron Technology

MT47H512M4EB-25E:C TR supplier

MT47H512M4EB-25E:C TR stock

RELATED PRODUCTS

Part#: MT47H32M16U67A3WC1

Description: IC DRAM 512M PARALLEL WAFER

25E:C TR in stock available now. Request a quote from electronics components distributor at Component-World.com, our sales team will contact you within 24 hours.

Part#: MT47H512M4THN-3:E TR

Description: IC DRAM 2G PARALLEL 63FBGA

Part#: MT47H512M4EB-25E:C

Part#: MT47H32M16NF-25E IT:H TR

Part#: MT47H512M4THN-37E:E TR

Description: IC DRAM 2G PARALLEL 60FBGA

Description: IC DRAM 512M PARALLEL 84FBGA

Part#: MT47H32M8BP-37E:B TR

Description: IC DRAM 2G PARALLEL 63FBGA

Part#: MT47H32M8BP-3:B TR

Description: IC DRAM 256M PARALLEL 60FBGA

Part#: MT47H32M16NF-25E:H

Description: IC DRAM 512M PARALLEL 84FBGA

Micron

Description: IC DRAM 256M PARALLEL 60FBGA

Part#: MT47H32M8BP-37V:B

Description: IC DRAM 256M PARALLEL 60FBGA

Part#: MT47H512M8WTR-25E:C TR

Description: IC DRAM 4G PARALLEL 63FBGA

Part#: MT47H512M4THN-25E:M

Description: IC DRAM 2G PARALLEL 400MHZ

Part#: MT47H32M8BP-5E:B

Description: IC DRAM 256M PARALLEL 60FBGA

Part#: MT47H512M8WTR-25E:C

Description: IC DRAM 4G PARALLEL 63FBGA

Description: IC DRAM 256M PARALLEL 60FBGA

Description: IC DRAM 2G PARALLEL 63FBGA

Part#: MT47H32M8BP-5E:B TR

Part#: MT47H512M4THN-25E:M TR

Part#: MT47H512M4EB-3:C

Micron

Description: IC DRAM 2G PARALLEL 60FBGA

Part#: MT47H512M4EB-187E:C

Description: IC DRAM 2G PARALLEL 60FBGA

Part#: MT47H512M4THN-3:H

Part#: MT47H512M8WTR-3:C

Description: IC DRAM 2G PARALLEL 63FBGA

Description: IC DRAM 4G PARALLEL 63FBGA

Description: IC DRAM 2G PARALLEL 63FBGA

Micron Technology MT47H512M4EB-25E:C TR

MT47H512M4EB-25E:C TR download datasheet

Micron Technology MT47H512M4EB-25E:C TR

Part#: MT47H512M4THN-25E:H

Related keywords for MT47H512M4EB-25E:C TR

ISO



MT47H512M4EB-25E:C TR price

buy MT47H512M4EB-25E:C TR







MT47H512M4EB-25E:C TR distributor

MT47H512M4EB-25E:C TR datasheet

Micron Technology Inc. MT47H512M4EB-25E:C TR